KBJ2006G-KBJ2008G

20A STANDARD RECOVERY BRIDGE RECTIFIER

Product Summary

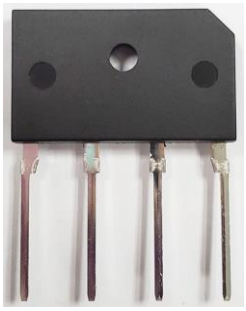
V_{RRM} (V)	I_F (A)	V_F Max (V) @ I_F = 10A	I_R Max (µA)
600, 800	20	1.1	5

Features

- Glass Passivated Die Construction
- Rating to 1000V PRV
- Ideal for Printed Circuit Board
- Reliable Low Cost Construction Utilizing Molded Plastic Technique
- UL Recognized File # E94661
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.**
  https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: KBJ
- Package Material: Plastic Material, UL Flammability Classification 94V-0
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 e3
- Polarity Indicator: As Marked on The Body
- Weight: 4.6 grams (Approximate)
- Mounting Position: Any

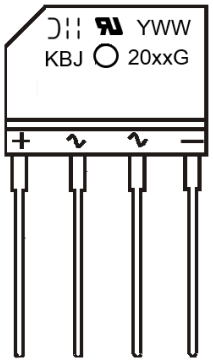


Ordering Information (Note 4)

Part Number	Qualification	Package	Packing	
			Qty.	Carrier
KBJ2006G-TU	Commercial	KBJ	20pcs	Tube
KBJ2008G-TU	Commercial	KBJ	20pcs	Tube

Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



KBJ20xxG = Product Type Marking Code
= Manufacturer's Code Marking
YWW = Date Code Marking
Y = Last Digit of Year (ex: 1 = 2021)
WW = Week Code (01 to 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	KBJ2006G	KBJ2008G	Unit
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	600	800	V
Maximum DC Blocking Voltage	V_{DC}	600	800	V
Average Rectified Output Current @T_C = +110°C With Heatsink / Without Heatsink	$I_{F(AV)}$	20 / 3.0		A
Peak Forward Surge Current 8.3ms Single Half Sine-Wave T_J = +25°C	I_{FSM}	200		A
I^2t Rating for Fusing (t = 8.3ms)	I^2t	166		A^2s
Mounting Torque (Recommended Torque: 0.5 N.m)	TOR	0.8		N.m
Operating Temperature Range	T_J	-55 to +150		°C
Storage Temperature Range	T_{STG}	-55 to +150		°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Test Condition	Symbol	Max	Unit
Forward Voltage	I_F = 10A T_J = +25°C	V_F	1.1	V
Leakage Current	V_R at Rated T_J = +25°C / T_J = +125°C	I_R	5.0 / 500	μA
Typical Junction Capacitance (Note 5)		C_J	70	pF

Thermal Characteristics

Characteristic	Symbol	Typ.	Unit
Typical Thermal Resistance (Note 6)	$R_{\theta JC}$	0.8	°C/W

Notes: 5. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
6. Device mounted on 250mm*250mm*20mm aluminum plate heatsink, T_A = +25°C.

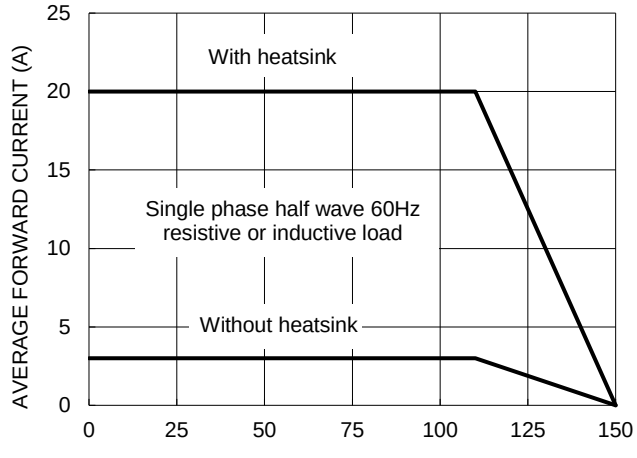


Figure 1. Forward Current Derating Curve

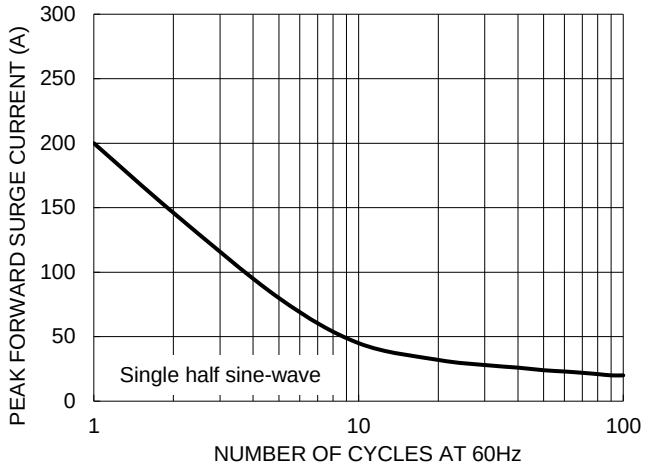


Figure 2. Maximum Non-repetitive Surge Current

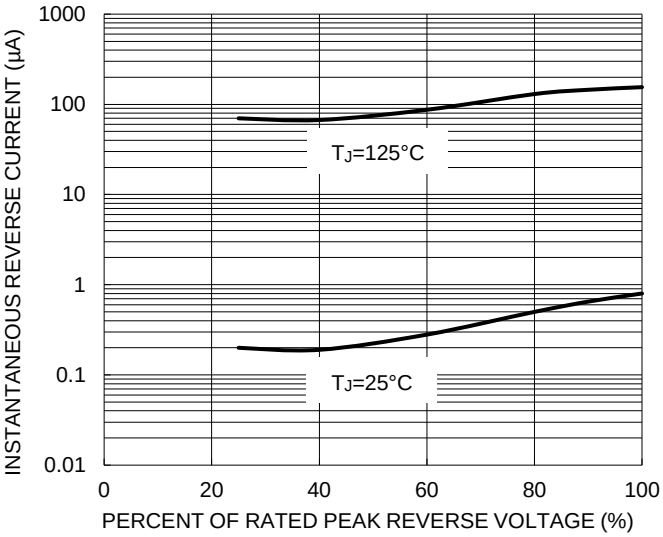


Figure 3. Typical Reverse Characteristics

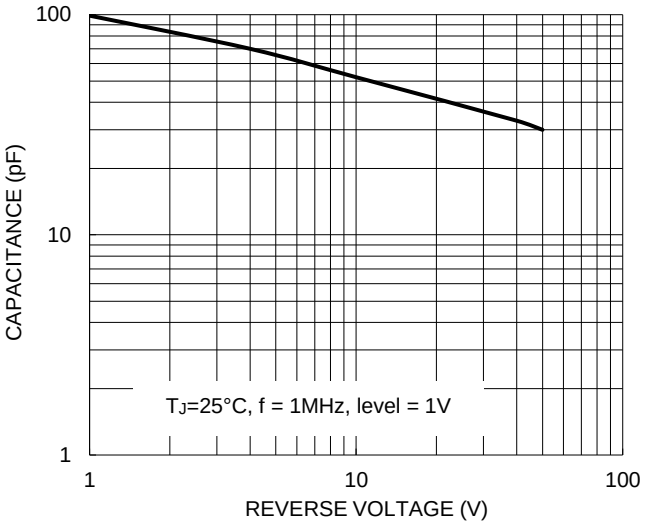


Figure 4. Typical Junction Capacitance

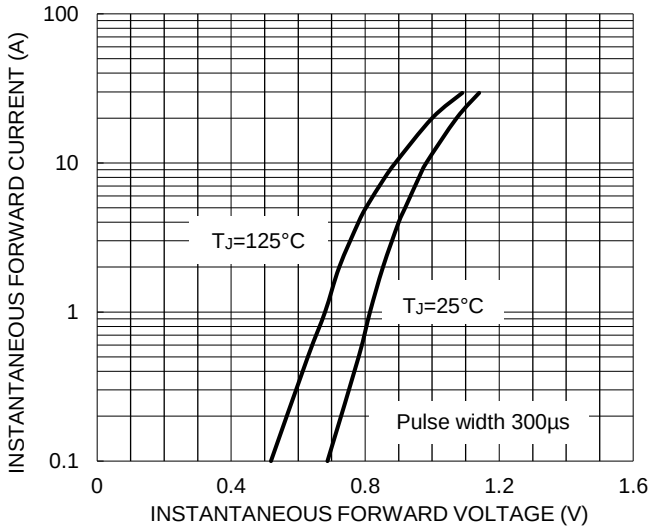
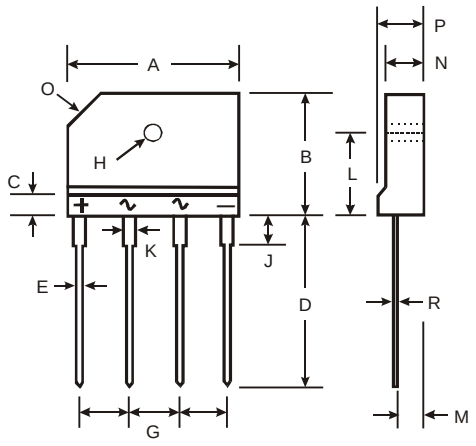


Figure 5. Typical Forward Characteristics

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

KBJ



KBJ		
Dim	**Min**	**Max**
A	24.80	25.20
B	14.70	15.30
C	3.90	4.10
D	17.20	17.80
E	0.90	1.10
G	7.30	7.70
H	3.10∅	3.40∅
J	3.30	3.70
K	1.50	1.90
L	9.30	9.70
M	2.50	2.90
N	3.40	3.80
O	3.0 x 45°	
P	4.40	4.80
R	0.60	0.80
All Dimensions in mm		

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